SB80W06T

ON Semiconductor®

http://onsemi.com

Schottky Barrier Diode

60V, 8A, Low IR, Monolithic Dual TP Common Cathode

Applications

· High frequency rectification (switching regulators, converters, choppers)

Features

- Low forward voltage (VF max=0.6V)
- · Low switching noise
- · Halogen free compliance

- · Fast reverse recovery time
- · High reliability due to highly reliable planar structure

Specifications

Absolute Maximum Ratings at Ta=25°C

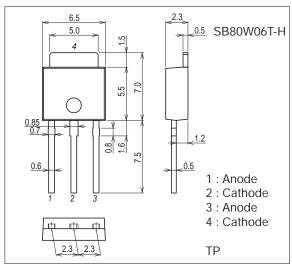
Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	VRRM		60	V
Nonrepetitive Peak Reverse Surge Voltage	V _{RSM}		66	V

Continued on next page.

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

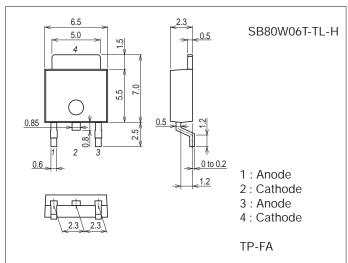
Package Dimensions

unit: mm (typ) 7518-001



Package Dimensions

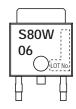
unit: mm (typ) 7003-002



Product & Package Information

- Package: TP
- JEITA, JEDEC: SC-64, TO-251, SOT-553, DPAK
- Minimum Packing Quantity: 500 pcs./bag

Marking (TP, TP-FA)



- Package: TP-FA
- JEITA, JEDEC: SC-63, TO-252, SOT-428, DPAK
- Minimum Packing Quantity: 700 pcs./reel

Packing Type (TP-FA): TL

Semiconductor Components Industries, LLC, 2013

September, 2013

Electrical Connection

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Continued from preceding page.

Parameter	Symbol	Conditions	Ratings	Unit
Average Output Current	I _O *2	50Hz resistive load, sine wave Tc=130°C	4	А
Average Output Current Io*1		50Hz resistive load, sine wave Tc=83°C	8	А
Surge Forward Current	I _{FSM}	50Hz sine wave, 1 cycle	40	А
Junction Temperature	Tj		-55 to +150	°C
Storage Temperature	Tstg		-55 to +150	°C

Note) *1. Indicates the total value

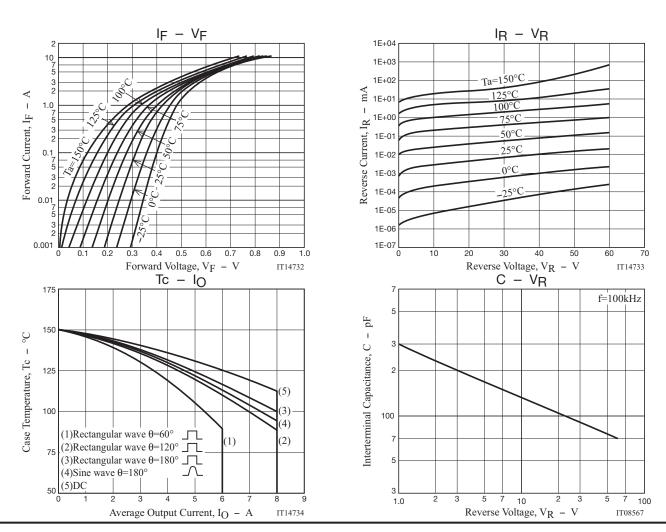
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit	
Parameter	Syllibol	Conditions	min	typ	max	Offic	
Reverse Voltage	VR	I _R =1mA, Tj=25°C *2	60			V	
Forward Voltage	VF	I _F =3.0A, Tj=25°C *2			0.6	V	
Reverse Current	IR	V _R =30V, Tj=25°C *2			0.1	mA	
Interterminal Capacitance	С	V _R =10V, Tj=25°C *2		130		pF	
Transient Thermal Resistance	Rth(j-c)	Junction-Case : Smoothed DC		6		°C / W	

Note) *2. Value per element

Ordering Information

Device	Package	Shipping	memo
SB80W06T-H	TP	500pcs./bag	Dh Fron and Halagan Fron
SB80W06T-TL-H	TP-FA	700pcs./reel	Pb Free and Halogen Free

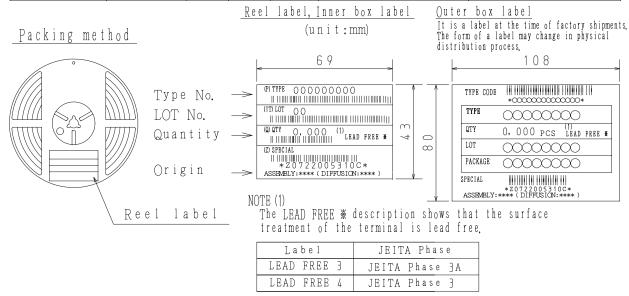


^{*2.} Value per element

Taping Specification SB80W06T-TL-H

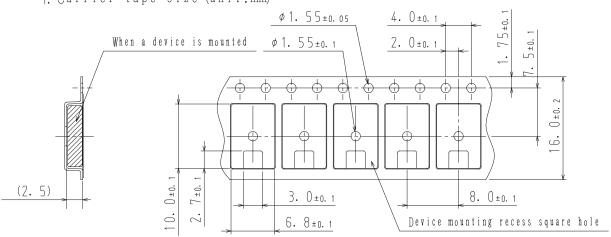
Packing Format

Package Name	Carrier Tape	Maximum Number of devices contained (pcs)			Packing	format
	Туре	Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX $(A-7)$
TP-FA	TP	700	2, 100	12,600	3 reels contained	6 inner boxes contained
					Dimensions:mm (external)	Dimensions:mm (external)
					183×72×185	440×195×210

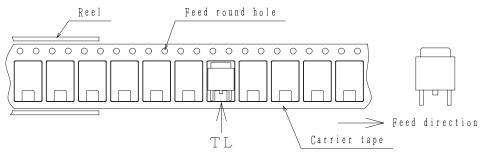


Taping configuration

1. Carrier tape size (unit:mm)



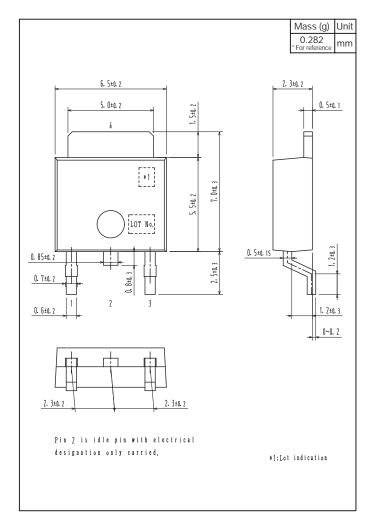
7. Device placement direction

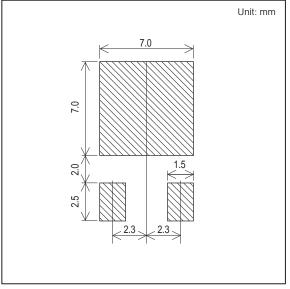


Those with one electrode terminal on the feed hole side · · · · · TL

Outline Drawing SB80W06T-TL-H

Land Pattern Example



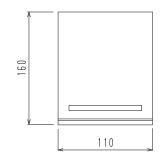


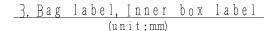
Bag Packing Specification SB80W06T-H

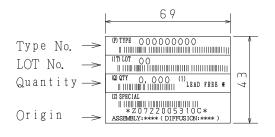
1. Packing Format

Package Name		Maximum Number of devices contained (pcs)					
1 4 0 11 4 5 0 1 1 4 4 11 0	Bag	Inner box	Outer box				
TP		B-1	A-1	A-2			
11	500	10,000	50,000	30,000			
		Packing fo	ormat (Dimensions:mm (external))				
		Inner box	Outer box				
B-1 445×225×55		B-1	A-1	A-2			
		470×250×300	470×250×190				

2. Bag dimensions (unit:mm)





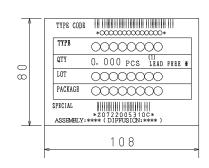


4. Outer box label (unit:mm)

It is a label at the time of factory shipments, The form of a label may change in physical distribution process,

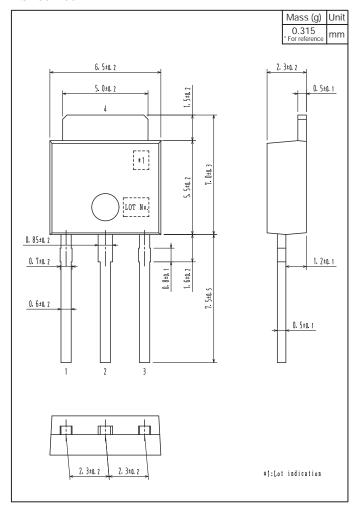


	Label			JEITA Phase
	LEAD	FREE	3	JEITA Phase 3A
Ī	LEAD	FREE	4	JEITA Phase 3



Outline Drawing

SB80W06T-H



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